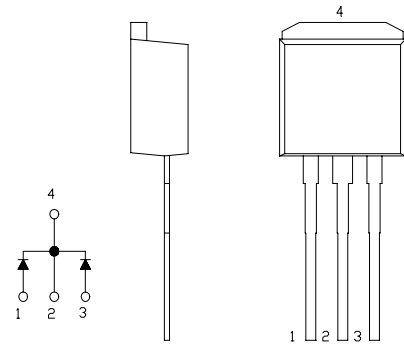


FRD Type : C16T20F-11A

OUTLINE DRAWING

FEATURES

- * **SQUARE-PAK** TO263AB Case (SMD)
- Packaged in 24mm Tape and Reel
- * Dual Diodes – Cathode Common
- * Ultra – Fast Recovery
- * Low Forward Voltage Drop
- * High Surge Capability
- * 200 Volts thru 600 Volts Types Available



Maximum Ratings

Approx Net Weight:1.4g

| Rating | Symbol | C16T20F-11A | | Unit |
|--------------------------------------|--------------|---------------|--|------------------|
| Repetitive Peak Reverse Voltage | V_{RRM} | 200 | | V |
| Non-repetitive Peak Reverse Voltage | V_{RSM} | 220 | | V |
| Average Rectified Output Current | I_O | 16 | $T_c=113^\circ\text{C}$ 50 Hz, Full Sine Wave Resistive Load | A |
| RMS Forward Current | $I_{F(RMS)}$ | 18 | | A |
| Surge Forward Current | I_{FSM} | 120 | 50 Hz Full Sine Wave, 1 cycle Non-repetitive | A |
| Operating Junction Temperature Range | T_{jw} | - 40 to + 150 | | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | - 40 to + 150 | | $^\circ\text{C}$ |

Electrical • Thermal Characteristics

| Characteristics | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|-----------------------|---------------|--|------|------|------|---------------------------|
| Peak Reverse Current | I_{RM} | $T_j=25^\circ\text{C}, V_{RM}=V_{RRM}$ per Arm | - | - | 25 | μA |
| Peak Forward Voltage | V_{FM} | $T_j=25^\circ\text{C}, I_{FM}=8\text{A}$ per Arm | - | - | 0.98 | V |
| Reverse Recovery Time | t_{rr} | $I_{FM}=8\text{A}$, $-di/dt=50\text{A}/\mu\text{s}$, $T_a=25^\circ\text{C}$ | - | - | 35 | ns |
| Thermal Resistance | $R_{th(j-c)}$ | Junction to Case | - | - | 2 | $^\circ\text{C}/\text{W}$ |

C16T20F-11A OUTLINE DRAWING (Dimensions in mm)

